



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re Patent Application of

NAKAMURA et al

Atty. Ref.: 160-399; Confirmation No. 1183

Appl. No. 10/718,652

TC/A.U. 2822

Filed: November 24, 2003

Examiner: Ida Soward

For: NITRIDE SEMICONDUCTOR WITH ACTIVE LAYER OF QUANTUM WELL  
STRUCTURE WITH INDIUM-CONTAINING NITRIDE SEMICONDUCTOR

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June 22, 2006

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

**AMENDMENT**

In response to the Office Action dated December 22, 2005, please amend the  
above-identified application as follows: